Defects in metals and alloys at finite temperatures from DFT

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- defects are always there
- defects modify material properties
- need to control defects
- need to understand defects

Defects:

point defects (vacancies)

stacking fault energies

anti-phase boundaries

surfaces

our most favorite ab initio simulations

(mine: periodic, plane-wave density functional theory, mostly VASP)



- typical experiments at **finite** temperatures
- usual applications at **finite** temperatures
- processing often at high temperatures (specifically metals)
- need extension from 0K to finite T DFT

energy → Helmholtz (free) energy Gibbs energy (pressure included)







- → largest contribution from (quasiharmonic) vibrations
- → BUT: other contributions important for phase stability, thermodynamic properties











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- → BUT: other contributions important for phase stability, thermodynamic properties





Quasiharmonic vibrations

Quasiharmonic approximation



e.g.: Wallace, Thermodynamics of Crystals (Dover, 1998).



Combination (DFT + quasiharmonic approximation) since ≈ 1989: Ref.: Biernacki und Scheffler, *PRL* **63**, 290 (1989).

$$F^{qh}(T,V) = E_{T=0K}(V) + \sum_{q}^{BZ} \sum_{i}^{3} \left[\frac{1}{2} \hbar \omega_{q,i}(V) + k_{B}T \ln \left[1 - \exp \left(-\frac{\hbar \omega_{q,i}(V)}{k_{B}T} \right) \right] \right]$$

Phonons for fcc metals





Phonons for fcc metals



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Electronic excitations



Mermin, Phys. Rev. 137, A1441 (1965)



$$F^{\text{el}} = k_{\text{B}}T \int N(E) \left[f \ln f + (1 - f) \ln(1 - f) \right] dE$$

ideal entropy

Electronic excitations, wide range study





Trends in the periodic table



Phys. Rev. B 95 (2017) 165126

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Electronic excitations, wide range study







important for phase stabilities

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 \rightarrow Very strong broadening

 \rightarrow Thermal disorder

 \rightarrow Localization

Example for tungsten



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Impact on electronic free energies

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Anharmonic vibrations





Example: Heat capacity of TiN

- → anharmonic (phononphonon interaction) contribution can be very important
- \rightarrow many such examples
- → anharmonicity cannot be neglected in general!

Reference: Forslund, Grabowski et al., PHYSICAL REVIEW B 103, 195428 (2021)

Heat capacity of silver





Phys. Rev. Lett. 114 (2015) 195901

Wide range study of heat capacities





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Phys. Rev. Lett. 114 (2015) 195901

Phys. Rev. Lett. 114 (2015) 195901

Magnetic excitations

Magnetic excitations (dreaming of what could be)

Example: Heat capacity for iron

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- mean-field approximation if well above Curie temperature
- or empirical approach with DFT/experimental input

$$C^{\text{mag}}(T) = \begin{cases} k_f(T/T_C) \exp[-4(1 - T/T_C)] & T < T_C \\ k_p(T/T_C) \exp[8p(1 - T/T_C)] & T > T_C \end{cases}$$

$$S^{\text{mag}} = k_B \ln(m+1).$$

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Back to defects

"master" equation: ox energy volume okeneroywohum defect Free energy (meV/atom) Free energy (meV/atom) defect perfect formation -500 -500 -1000 -1000 free energy Volume Volume 500 (Å³/atom) 500 (Å³/atom) 1000 1000 Temperature (K) Temperature (K) 1500 1500 T_{melt} (exp) Tmelt (exp)

- \rightarrow once you have anharmonic vibrations, do not care much about defects
- \rightarrow but supercell size convergence can be tough (error scales with # atoms)
- \rightarrow and sometimes special care necessary, e.g.:
 - stacking plane migration
 - vacancy migration

Stacking plane migration

ANNNI = axial-next-nearest- neighbor-Ising

Example: hcp Ni for ANNNI model (SFE = hcp – fcc)

Phys. Rev. B 98 (2018) 224106

- \rightarrow MD needs to be monitored carefully
- \rightarrow here finite size effects play a role
- \rightarrow supercell size needs to be large enough

Most recent method for finite temperature DFT

Methodology: Direct upsamling

(to be published)

- 1. Run low accuracy DFT molecular dynamics
- 2. Fit preliminary moment tensor potential (MTP)
- 3. Optimize MTP on high accuracy DFT snapshots
- 4. TILD from effective harmonic to MTP for F(V,T)
- 5. Upsampling from MTP to DFT on snapshots for F(V,T)
- 6. Parametrize $F(V,T) \rightarrow Legendre transform to G(P,T)$
- 7. Extract thermodynamic properties (e.g. heat capacity, expansion coefficient, bulk modulus)

TILD = thermodynamic integration using Langevin dynamics

Moment tensor potentials (MTPs)

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Shapeev, Multiscale Modeling & Simulation 14, 1153 (2016)

Descriptors of atomic environments:

- Moments of inertia of surrounding atoms
- They satisfy the needed symmetries (rotation, permutation, translation, ...)
- Math:

> Moments: $M_{n,m}(\boldsymbol{r_{i}}) = \sum_{j} f_n(|r_{ij}|) r_{ij} \otimes \cdots \otimes r_{ij}$

m times

 \succ Energy: $E = \sum_{\alpha} \theta_{\alpha} B_{\alpha}$

Active learning via D-optimality

included: anharmonic vibrations, electronic excitations, coupling, magnetism (mean field, empirical)

Defects: Results

Arrhenius or not Arrhenius

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Phys. Rev. X 4 (2014) 011018

Arrhenius or not Arrhenius

Phys. Rev. X 4 (2014) 011018

Physical insight

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Nearest neighbor distribution at finite temperatures

→ Localized interactions around vacancy

Vacancies in Ni

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Stacking fault energy for Nickel

Stacking fault energy for Nickel

Ni₃Al APB important for Ni-superalloys (to be published)

Surface free energy of TiN (very important for coatings)

 \rightarrow high accuracy surface properties possible

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Alloys

Unary system (single element)

 \rightarrow single defect formation energy

Chemically complex system High entropy alloy VNbMoTaW

→ MANY defect formation energies (distribution)
 → highly challenging already at 0K

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Vacancy energetics from unaries to alloys

Al

C Hf

Sc Sc

TiZr

[-100]

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Configurational vacancy excitations

Equilibrium vacancy concentration

Ref: Xi Zhang, B. Grabowski (under review)

Future challenges

Summary

- key: free energy surface, for bulk & defects
- various excitations (qh, ah, el, mag, coupling)
- explicit anharmonic vibrations crucial
- efficient methodology: direct upsampling
- utilizes machine learning potentials
- generally good agreement with experiment
- predictions possible, understanding possible

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